MAX3469xxA Rev. A

**RELIABILITY REPORT** 

FOR

### MAX3469xxA

PLASTIC ENCAPSULATED DEVICES

January 14, 2004

# MAXIM INTEGRATED PRODUCTS

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### Conclusion

The MAX3469 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. .....Device Description II. .....Manufacturing Information III. .....Packaging Information V. ......Quality Assurance Information VI. .....Reliability Evaluation IV. .....Die Information .....Attachments

### I. Device Description

#### A. General

The MAX3469 is a high-speed differential bus transceiver for RS-485 and RS-422 communications. It is designed to meet TIA/EIA-422-B, TIA/EIA-485-A, V.11, and X.27 standards. The transceiver complies with the Profibus specification providing +2.1V minimum output level with a 54Ω load, 40Mbps data rate, and output skew less than 2ns. The part contains one three-state differential line driver and one differential input line receiver. The device operates from a +5V supply and feature true fail-safe circuitry, which guarantees a logic-high receiver output when the receiver inputs are open or shorted. This enables all receiver outputs on a terminated bus to output logic highs when all transmitters are disabled.

The device features a 1/4-standard-unit load receiver input impedance that allows 128 transceivers on the bus. Driver and receiver propagation delays are guaranteed under 20ns for multidrop, clock distribution applications. Drivers are short-circuit current limited and are protected against excessive power dissipation by thermal-shutdown circuitry. The driver and receiver feature active-high and active-low enables, respectively, that can be connected together externally to serve as a direction control.

B. Absolute Maximum Ratings	
ltem	Rating
Supply Voltage (VCC) to GND	-0.3V to +6V
Control Input Voltage (RE, DE, DI, SHDN, TXP, RXP) to GND	-0.3V to (VCC + 0.3V)
Driver Output Voltage (Y, Z) to GND	-8V to +13V
Receiver Input Voltage (A, B) to GND	-8V to +13V
Differential Driver Output Voltage (Y - Z)	±8V
Differential Receiver Input (A - B)	±8V
Receiver Output Voltage (RO) to GND	-0.3V to (VCC + 0.3V)
Output Driver Current (Y, Z)	±250mA
Operating Temperature Range	
MAX3469C	0°C to +70°C
MAX3469E	-40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Continuous Power Dissipation (TA = +70°C)	
8-Pin NSO	471mW
8-Pin PDIP	727mW
Derates above +70°C	
8-Pin NSO	5.88mW/°C
8-Pin PDIP	9.09mW/°C

# II. Manufacturing Information

A. Description/Function:	+5V, Fail-Safe, 40Mbps, Profibus RS-485/RS-422 Transceivers
B. Process:	B8 (Standard 0.8 micron silicon gate CMOS)
C. Number of Device Transistors:	610
D. Fabrication Location:	California, USA
E. Assembly Location:	Malaysia, Philippines or Thailand
F. Date of Initial Production:	October, 2003

# III. Packaging Information

A. Package Type:	8-Pin NSO	8-Pin PDIP
B. Lead Frame:	Copper	Copper
C. Lead Finish:	Solder Plate	Solder Plate
D. Die Attach:	Conductive Epoxy	Conductive Epoxy
E. Bondwire:	Gold (1 mil dia.)	Gold (1 mil dia.
F. Mold Material:	Epoxy with silica filler	Epoxy with silica filler
G. Assembly Diagram:	# 05-9000-0821	# 05-9000-0822
H. Flammability Rating:	Class UL94-V0	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard JESD22-112:	Level 1	Level 1

### IV. Die Information

A. Dimensions:	71 x 71 mils
B. Passivation:	$Si_3N_4/SiO_2$ (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Aluminum/Si (Si = 1%)
D. Backside Metallization:	None
E. Minimum Metal Width:	0.8 microns (as drawn)
F. Minimum Metal Spacing:	0.8 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO <sub>2</sub>
I. Die Separation Method:	Wafer Saw

### V. Quality Assurance Information

Α.	Quality Assurance Contacts:	Jim Pedicord (Manager, Reliability Operations)
		Bryan Preeshl (Executive Director of QA)
		Kenneth Huening (Vice President)

- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

#### VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

 $\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{1.83}_{192 \text{ x } 4389 \text{ x } 50 \text{ x } 2}$ (Chi square value for MTTF upper limit) Temperature Acceleration factor assuming an activation energy of 0.8eV

 $\lambda = 21.72 \times 10^{-9}$ 

 $\lambda$  = 21.72 F.I.T. (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability monitor program. In addition to routine production Burn-In, Maxim pulls a sample from every fabrication process three times per week and subjects it to an extended Burn-In prior to shipment to ensure its reliability. The reliability control level for each lot to be shipped as standard product is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on any lot that exceeds this reliability control level. Attached Burn-In Schematic (Spec. # 06-5783) shows the static Burn-In circuit. Maxim also performs quarterly 1000 hour life test monitors. This data is published in the Product Reliability Report (**RR-1M**).

### B. Moisture Resistance Tests

Maxim pulls pressure pot samples from every assembly process three times per week. Each lot sample must meet an LTPD = 20 or less before shipment as standard product. Additionally, the industry standard 85°C/85%RH testing is done per generic device/package family once a quarter.

### C. E.S.D. and Latch-Up Testing

The RT82-4 die type has been found to have all pins able to withstand a transient pulse of  $\pm 200V$  per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of  $\pm 250$ mA.

### Table 1 Reliability Evaluation Test Results

#### MAX3469xxA

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	t (Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		50	0
Moisture Testir	ng (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	PDIP NSO	77 77	0 0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Str	ress (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0

Note 1: Life Test Data may represent plastic DIP qualification lots. Note 2: Generic Package/Process data

### Attachment #1

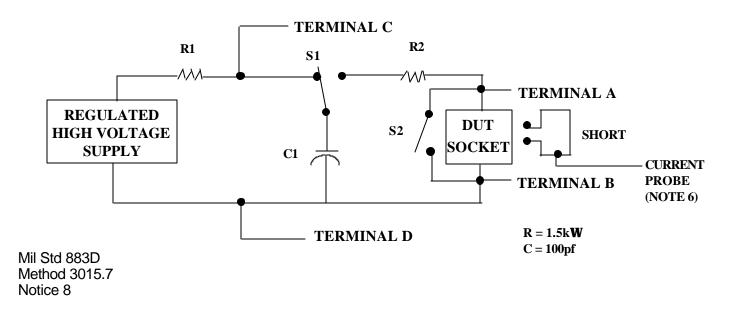
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)		
1.	All pins except V <sub>PS1</sub> <u>3/</u>	All $V_{PS1}$ pins		
2.	All input and output pins	All other input-output pins		

TABLE II. Pin combination to be tested. 1/2/

- 1/ Table II is restated in narrative form in 3.4 below.
- $\overline{2/}$  No connects are not to be tested.
- $\overline{3/}$  Repeat pin combination I for each named Power supply and for ground

(e.g., where  $V_{PS1}$  is  $V_{DD}$ ,  $V_{CC}$ ,  $V_{SS}$ ,  $V_{BB}$ , GND, + $V_{S}$ , - $V_{S}$ ,  $V_{REF}$ , etc).

- 3.4 <u>Pin combinations to be tested.</u>
  - a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
  - b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V<sub>SS1</sub>, or V<sub>SS2</sub> or V<sub>SS3</sub> or V<sub>CC1</sub>, or V<sub>CC2</sub>) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
  - c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



PKG. CODE: P8-1	SIGNATURES	DATE <b>MINIXI/VI</b> CONFIDENTIAL & PROPRIETARY
CAV./PAD SIZE: 100 X 100	PKG. DESIGN	BOND DIAGRAM #: REV:   05-9000-0822 A

PKG. CODE: S8-2		SIGNATURES	DATE	CONFIDENTIAL & PROPRIE	
CAV /PAD SIZE:	PKG.			BOND DIAGRAM #:	REV:
90 X 90	DESIGN			05-9000-0821	A

